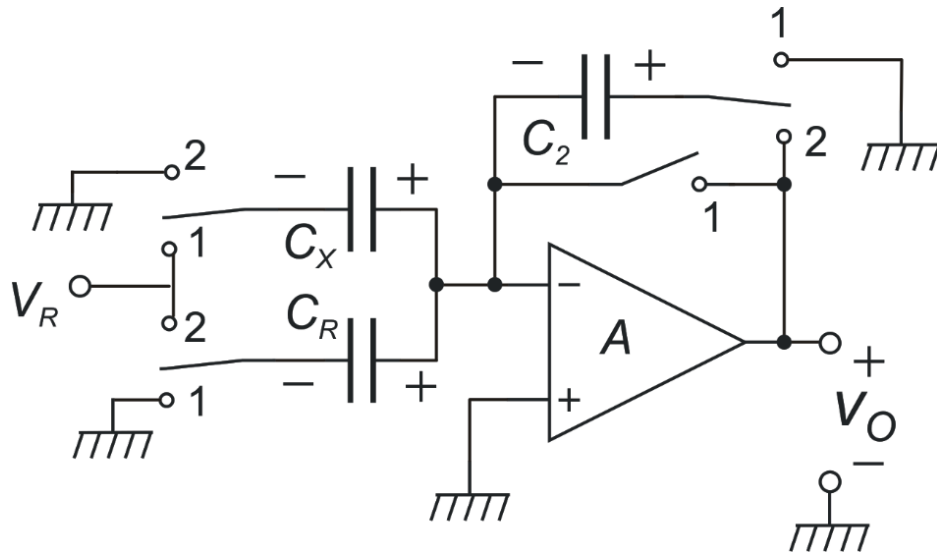


## SC charge amplifier design



Sensor:  
 $80 \text{ fF} \leq C_X \leq 180 \text{ fF}$   
 $C_R = 80 \text{ fF}$   
 $\Delta C_{FS} = 100 \text{ fF}$

Design choices:

$V_R = V_{dd} = 3.3 \text{ V}$  (ratiometric)  
 $C_2 = \Delta C_{FS} = 100 \text{ fF}$

$$V_{out}^{(2)} = \frac{\Delta C}{C_2} V_R$$

$$0 \leq V_{out}^{(2)} \leq V_{dd}$$

# Ratiometric systems

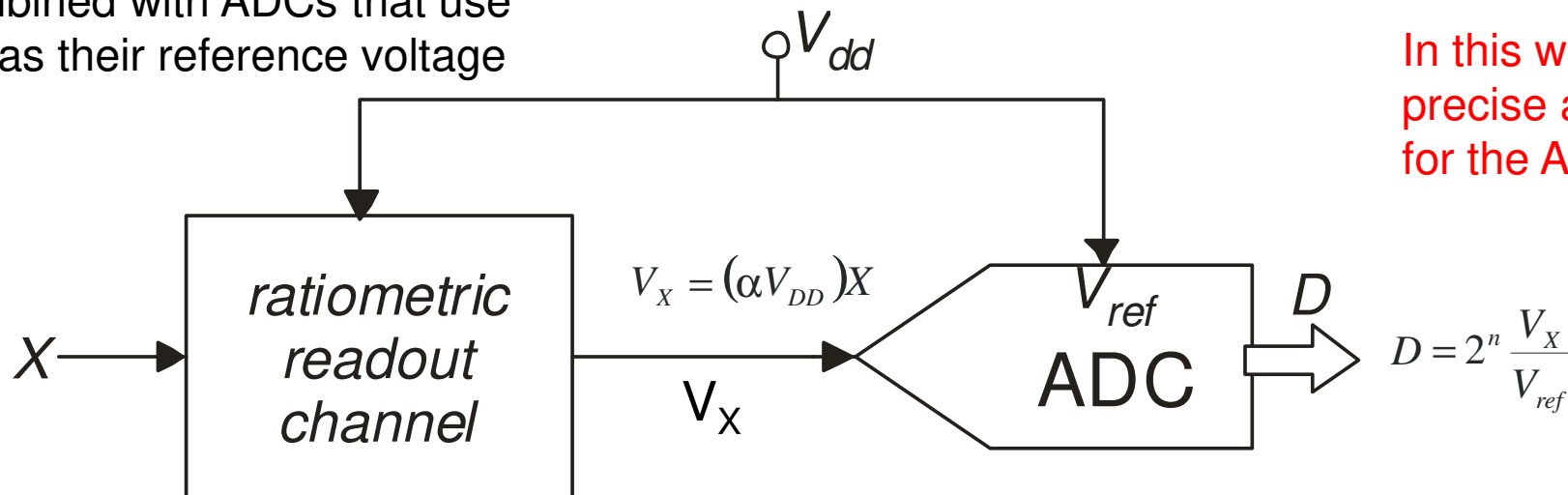
In a ratiometric system, the sensitivity is proportional to the supply voltage  $V_{dd}$ .

$$V_X = \underbrace{(\alpha V_{dd})}_{k_X} X$$

$$D = 2^n \frac{V_X}{V_{REF}} = 2^n \frac{(\alpha V_{dd}) X}{V_{dd}} = 2^n \alpha X$$

Ratiometric AFEs are often combined with ADCs that use  $V_{dd}$  as their reference voltage

In this way the need of a precise and stable  $V_{REF}$  for the ADC is removed



Dynamic range (only  $kT/C$  contribution is analyzed)

$$DR = \frac{V_R}{4\sqrt{kT / \Delta C_{FS}}} \sqrt{\frac{\Delta C_{FS}}{(C_2 + C_X + C_R)}} = 2174 \quad (66.7 \text{ dB}, 11.1 \text{ bit})$$

4125
0.527

worst case:  $C_X=180 \text{ fF}$

$$4\sqrt{\frac{kT}{\Delta C_{FS}}} \cong 4\sqrt{\frac{4 \times 10^{-21} \text{ J}}{100 \times 10^{-15} \text{ F}}} = 0.8 \text{ mV}$$

## Capacitance resolution

$$\Delta C_n = \frac{\Delta C_{FS}}{DR} = \frac{100 \text{ fF}}{2174} = 0.045 \text{ fF} = 45 \text{ aF}$$

Example: a pressure sensor with linear response, such that:

$$\left\{ \begin{array}{l} \Delta C = 0 \Rightarrow p = 0 \text{ Pa (0 mBar)} \\ \Delta C = 100 \text{ fF} \Rightarrow p = 200 \text{ kPa (2 Bar)} \end{array} \right.$$

$$\text{pressure resolution} = \delta p = \frac{\Delta p_{FS}}{DR} = \frac{200 \text{ kPa}}{2174} \cong 90 \text{ Pa (0.9 mBar)}$$

If we have a sensor with all capacitances scaled up by a factor of 10:

Sensor:  $0.8 \text{ pF} \leq C_X \leq 1.8 \text{ pF}$   
 $C_R = 0.8 \text{ pF}$   
 $\Delta C_{FS} = 1 \text{ pF}$

$$DR = \frac{V_R}{4 \sqrt{kT / \Delta C_{FS}}} \sqrt{\frac{\Delta C_{FS}}{(C_2 + C_X + C_R)}} = 6956 \quad (76.8 \text{ dB})$$

13200

same ratio as before 0.527

$$4 \sqrt{\frac{kT}{\Delta C_{FS}}} \cong 4 \sqrt{\frac{4 \times 10^{-21} \text{ J}}{1 \times 10^{-12} \text{ F}}} \cong 0.25 \text{ mV}$$

$$\text{capacitance resolution} = \Delta C_n = \frac{\Delta C_{FS}}{DR} = \frac{1 \text{ pF}}{6956} = 0.140 \text{ fF} = 140 \text{ aF}$$

# Use of an absolute pressure sensor as an altimeter



$$\frac{dp}{dh} = -\rho(p, T)g$$

USA National Oceanic and Atmospheric Administration

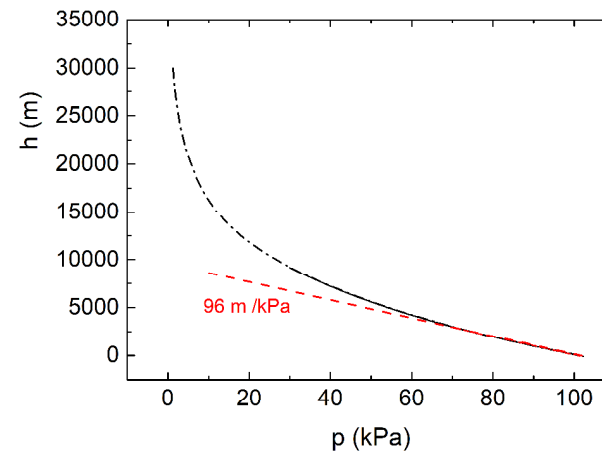
$$h \cong 44307.69 \left[ 1 - \left( \frac{p}{102325} \right)^{0.190284} \right]$$

Altitude resolution:

$$h_e = p_e \frac{\partial h}{\partial p} = 8.64 \text{ m}$$

$\nearrow$ 
 $\nwarrow$

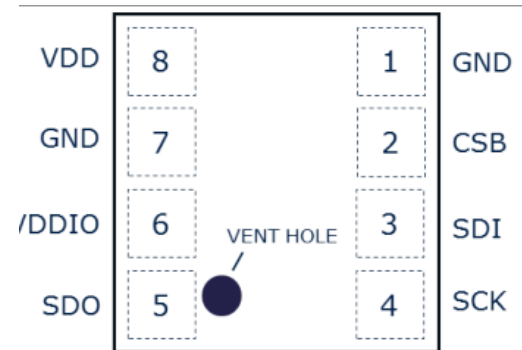
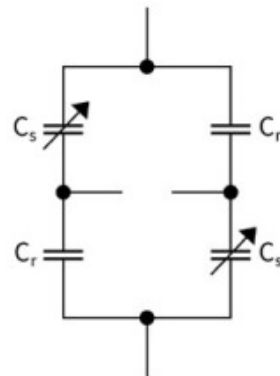
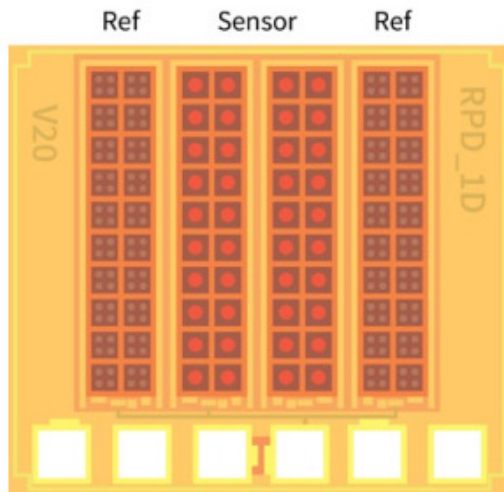
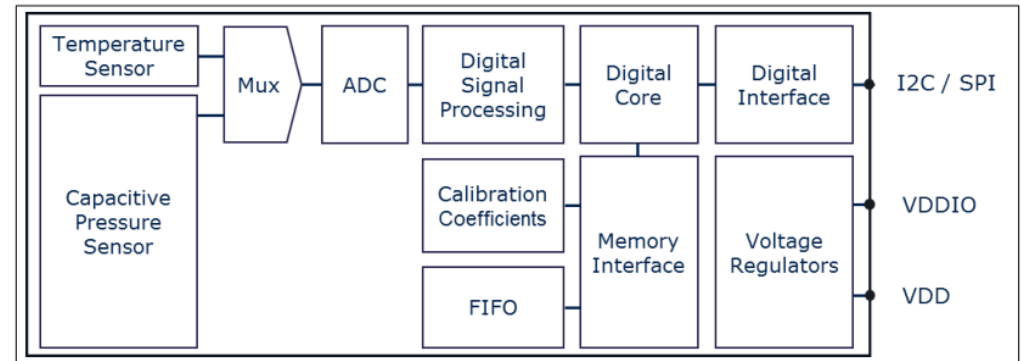
0.090 kPa
96 m /kPa





# Example of commercial capacitive pressure sensor

## DPS310 - Digital Pressure Sensor



# Infineon DPS 310 - Specifications

- **Operation range:** Pressure: 300 –1200 hPa. Temperature: -40 – 85 °C.
- **Pressure sensor precision:**  $\pm 0.005$  hPa (or  $\pm 0.05$  m) (high precision mode).
- **Relative accuracy:**  $\pm 0.06$  hPa (or  $\pm 0.5$  m)
- **Absolute accuracy:**  $\pm 1$  hPa (or  $\pm 8$  m)
- **Temperature accuracy:**  $\pm 0.5^\circ\text{C}$ .
- **Pressure temperature sensitivity:** 0.5Pa/K
- **Measurement time: Typical:** 27.6 ms for standard mode (16x). Minimum: 3.6 ms for low precision mode.
- **Average current consumption:** 1.7  $\mu\text{A}$  for Pressure Measurement, 1.5 $\mu\text{A}$  for Temperature measurement @1Hz sampling rate, Standby: 0.5  $\mu\text{A}$ .
- **Supply voltage:** VDDIO: 1.2 – 3.6 V, VDD: 1.7 – 3.6 V.

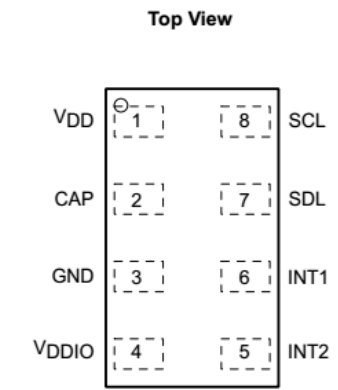
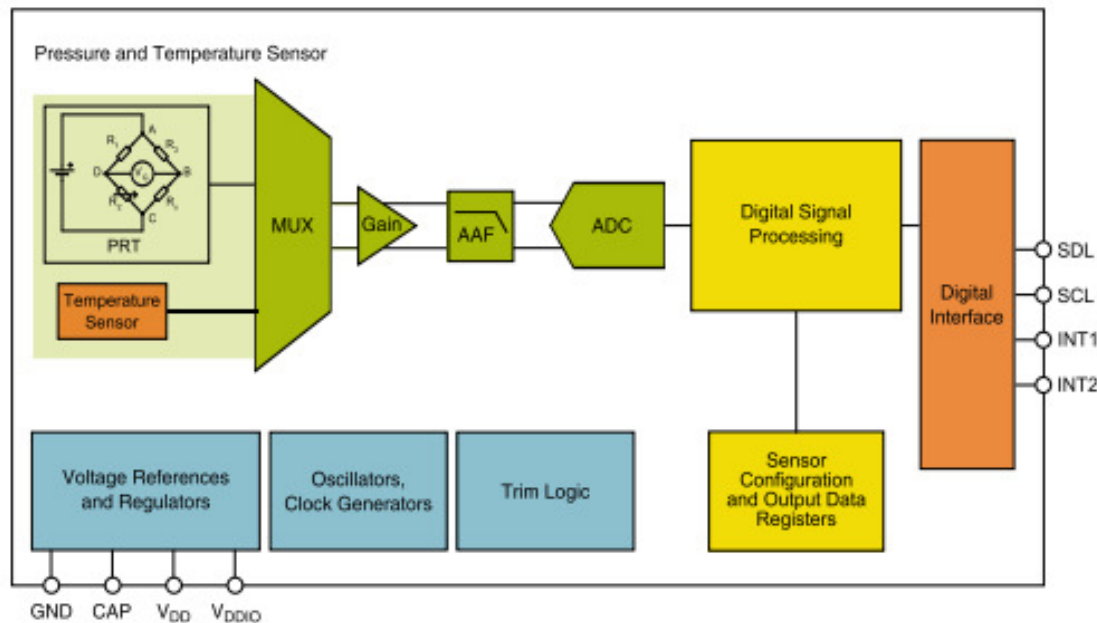
## Typical Applications

- **Indoor Navigation** (floor detection e.g. in shopping malls and parking garages)
- **Health and Sports** (accurate elevation gain and vertical speed)
- **Outdoor Navigation** (GPS start-up time and accuracy improvement, dead-reckoning e.g. in tunnels)
- **Weather Station** ('Micro-weather' and local forecasts)
- **HDD drivers**, (leak rate detection in hard disk drives)
- **Drones** (flight stability and height control)



# Example of piezoresistive pressure sensor

## Freescale (now NXP) **MPL3115A2** sensor



← I<sup>2</sup>C Digital Interface

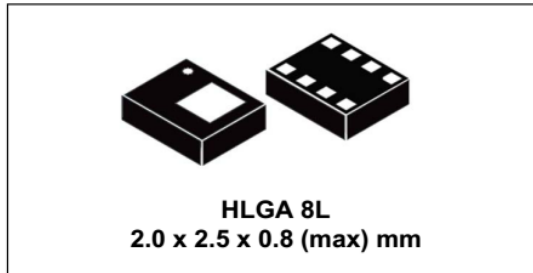
# MPL3115A2 Specifications

Accuracy is much worse than resolution, since it depends also on the offset and other quasi-static errors

128 samples are averaged to reduce noise

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
	Pressure Reading Noise	1x Oversample <sup>(2)</sup>		19		Pa RMS
		128x Oversample <sup>(2)</sup>		1.5		Pa RMS
P <sub>FS</sub>	Measurement Range	Calibrated Range	50		110	kPa
		Operational Range	20		110	kPa
	Pressure/Altitude Resolution <sup>(3)(4)(5)</sup>	Barometer Mode	0.25	1.5		Pa
		Altimeter Mode	0.0625	0.3		m
Pressure Absolute Accuracy	50 to 110 kPa over 0 °C to 50 °C	-0.4		0.4	kPa	
	50 to 110 kPa over -10 °C to 70 °C		±0.4			
V <sub>DD</sub>	Operating Supply Voltage		1.95	2.5	3.6	V

## Example of Piezoresistive sensor: STMicroelectronics **LPS225HB**



### Applications

- Altimeters and barometers for portable devices
- GPS applications
- Weather station equipment
- Sport watches

### Features

- 26 to 126 kPa absolute pressure range
- High-resolution mode: 1 Pa RMS
- Low-power mode: 3.5 Pa RMS
- Current consumption down to 4  $\mu$ A
- High overpressure capability: 20x full scale
- Embedded temperature compensation
- Embedded 24-bit ADC
- ODR from 1 Hz to 75 Hz
- SPI and I<sup>2</sup>C interfaces

Figure 1. Block diagram

